

## General Description

The WSR180N06 uses advanced SGT MOSFET to provide excellent  $R_{DS(ON)}$ , low gate charge

This device is suitable for use as a Battery protection or in other Switching application.

## Features

- 100% UIS +  $R_g$  Tested.
- Reliable and Rugged
- Lead Free and Green Devices Available (RoHS Compliant)
- Moisture Sensitivity Level MSL1 (per JEDEC J-STD-020D)

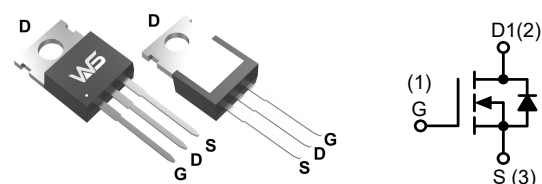
## Product Summary

$BV_{DSS}$	$R_{DS(ON)}$	$I_D$
60V	2.4m $\Omega$	150A

## Applications

- Power Management in Notebook Computer, Portable Equipment and Battery Powered Systems.

## TO-220-3L Pin Configuration



## Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$ , Unless Otherwise Noted)

Symbol	Parameter		Rating	Units
$V_{DS}$	Drain-Source Voltage		60	V
$V_{GS}$	Gate-Source Voltage		$\pm 20$	
$I_S$	Diode Continuous Forward Current	$T_C=25^{\circ}\text{C}$	155	A
$I_D$	Continuous Drain Current	$T_C=25^{\circ}\text{C}$	155	
		$T_C=100^{\circ}\text{C}$	117	
$I_{DM}^2$	Pulse Drain Current	$T_C=25^{\circ}\text{C}$	465	W
$P_D$	Maximum Power Dissipation	$T_C=25^{\circ}\text{C}$	250	
		$T_C=100^{\circ}\text{C}$	125	
$R_{\theta JA}^4$	Thermal Resistance-Junction to Ambient	Steady State	62.5	$^{\circ}\text{C/W}$
$R_{\theta JC}$	Thermal Resistance-Junction to Case		0.6	
$I_{AS}^3$	Avalanche Current, Single pulse	$L=0.5\text{mH}$	48	A
$E_{AS}^3$	Avalanche Energy, Single pulse	$L=0.5\text{mH}$	576	mJ
$T_{STG}$	Storage Temperature Range		-55 to 150	$^{\circ}\text{C}$
$T_J$	Maximum Junction Temperature		150	

**Electrical Characteristics** ( $T_A=25^{\circ}\text{C}$ , Unless Otherwise Noted)

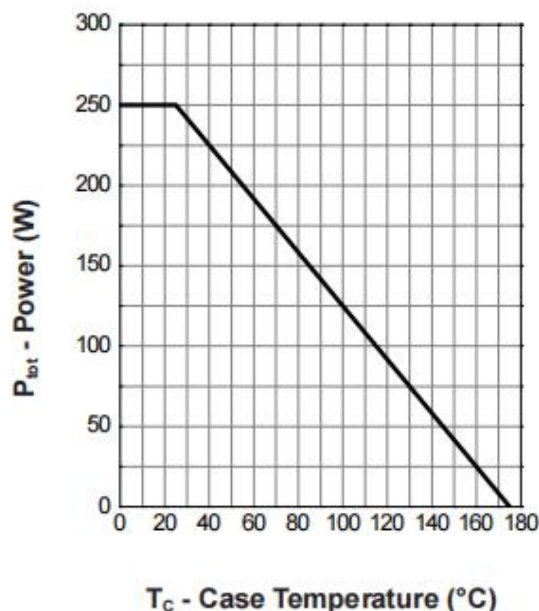
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
Static Characteristics						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =250μA	60	---	---	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =48V , V <sub>GS</sub> =0V T <sub>J</sub> =85°C	---	---	1.0 30	μA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>DS</sub> =250μA	2.0	3.0	4.0	V
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> =±20V , V <sub>DS</sub> =0V	---	---	±100	nA
R <sub>DS(ON)</sub> <sup>5</sup>	Drain-Source On-state Resistance	V <sub>GS</sub> =10V , I <sub>D</sub> =60A	---	2.4	2.6	mΩ
Diode Characteristics						
V <sub>SD</sub> <sup>5</sup>	Diode Forward Voltage	I <sub>SD</sub> =60A , V <sub>GS</sub> =0V	---	0.8	1.3	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>DS</sub> =60A , di <sub>SD</sub> /dt=100A/μs	---	71	---	ns
Q <sub>rr</sub>	Reverse Recovery Charge		---	103	---	nC
Dynamic Characteristics <sup>6</sup>						
R <sub>g</sub>	Gate Resistance	V <sub>GS</sub> =0V , V <sub>DS</sub> =0V , f=1.0MHz	---	1.8	---	Ω
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V , V <sub>DS</sub> =30V , Frequency=1.0MHz	---	3907	5350	pF
C <sub>oss</sub>	Output Capacitance		---	1154	---	
C <sub>rss</sub>	Reverse Transfer Capacitance		---	30	---	
T <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =30V , R <sub>L</sub> =30Ω , I <sub>DS</sub> =1A , V <sub>GEN</sub> =10V , R <sub>G</sub> =6Ω	---	31	---	ns
T <sub>r</sub>	Turn-on Rise Time		---	18	---	
T <sub>d(off)</sub>	Turn-off Delay Time		---	100	---	
T <sub>f</sub>	Turn-off Fall Time		---	195	---	
Gate Charge Characteristics <sup>6</sup>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =30V , V <sub>GS</sub> =10V , I <sub>DS</sub> =60A	---	93	---	nC
Q <sub>gs</sub>	Gate-Source Charge		---	24	---	
Q <sub>gd</sub>	Gate-Drain Charge		---	11.6	---	

**Note:**

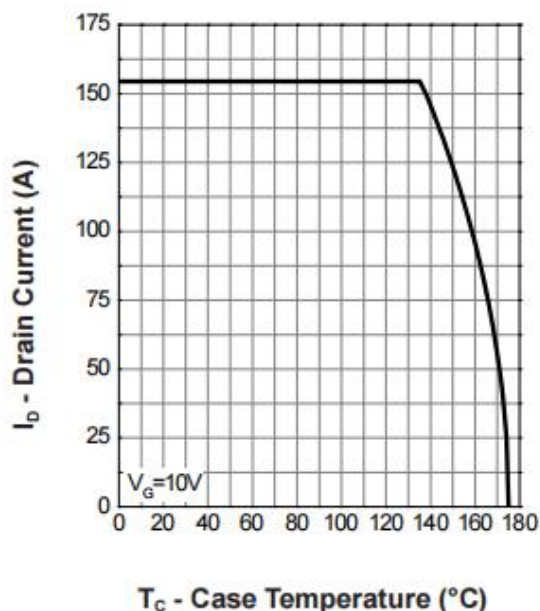
1. Calculated continuous current based on maximum allowable junction temperature. Bonding wire limitation current is 8A.
2. Pulse width limited by max. junction temperature.
3. UIS tested and pulse width limited by maximum junction temperature  $150^{\circ}\text{C}$  (initial temperature  $T_J=25^{\circ}\text{C}$ ).
4. Surface Mounted on  $1\text{in}^2$  pad area.
5. Pulse test ; pulse width $\leq 300\mu s$ , duty cycle $\leq 2\%$ .
6. Guaranteed by design, not subject to production testing.

## Typical Characteristics

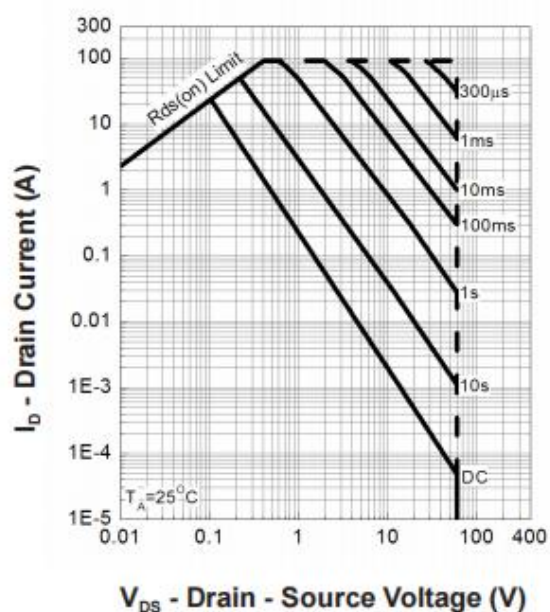
Power Dissipation



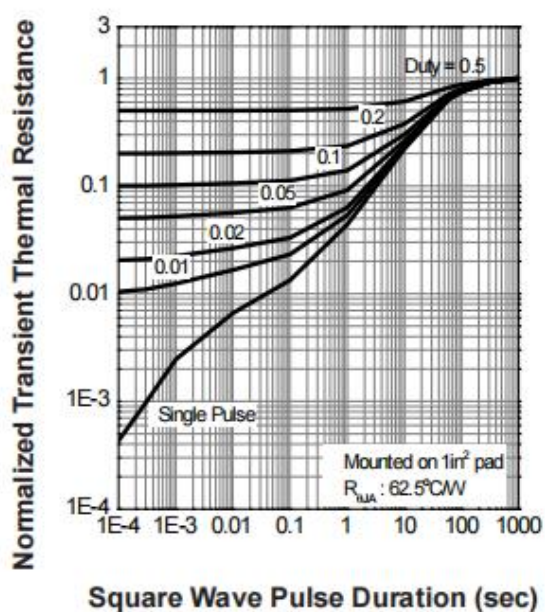
Drain Current



Safe Operation Area

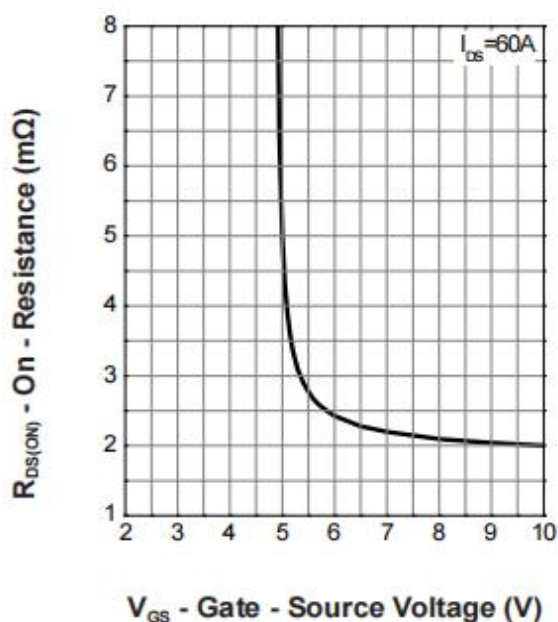


Thermal Transient Impedance

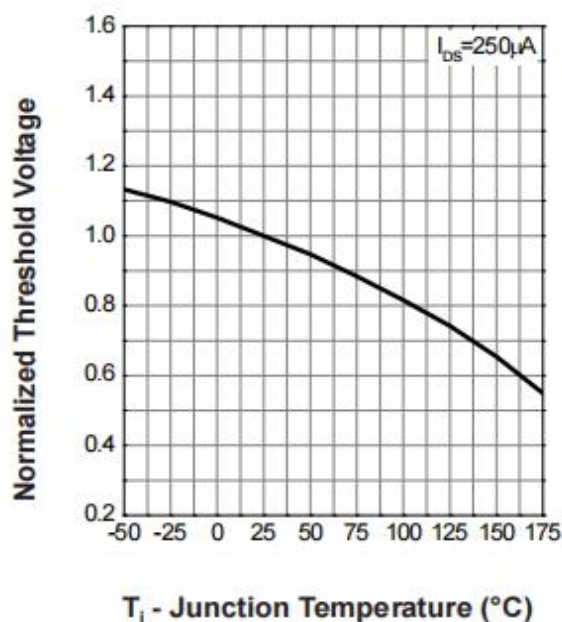


Typical Characteristics (Cont.)

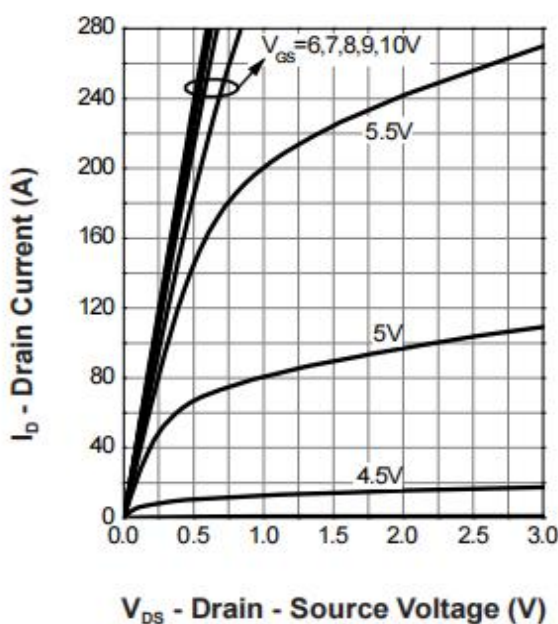
Gate-Source On Resistance



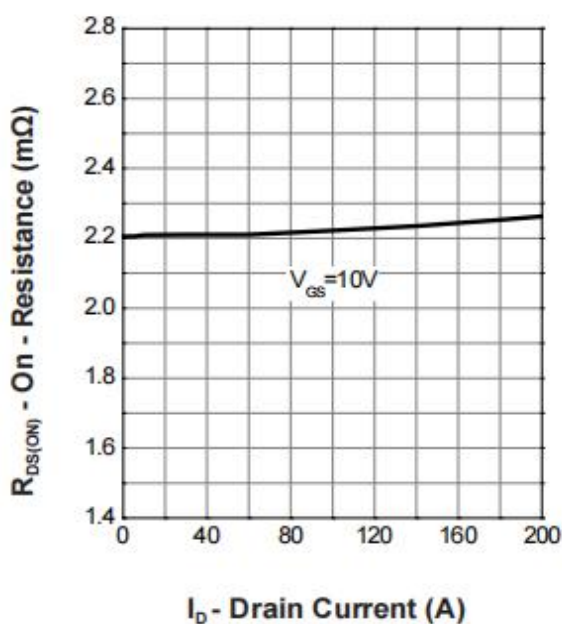
Gate Threshold Voltage



Output Characteristics



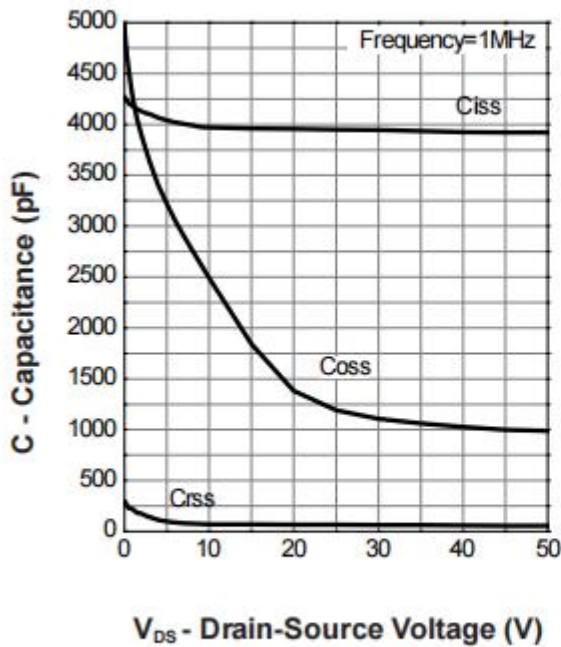
Drain-Source On Resistance



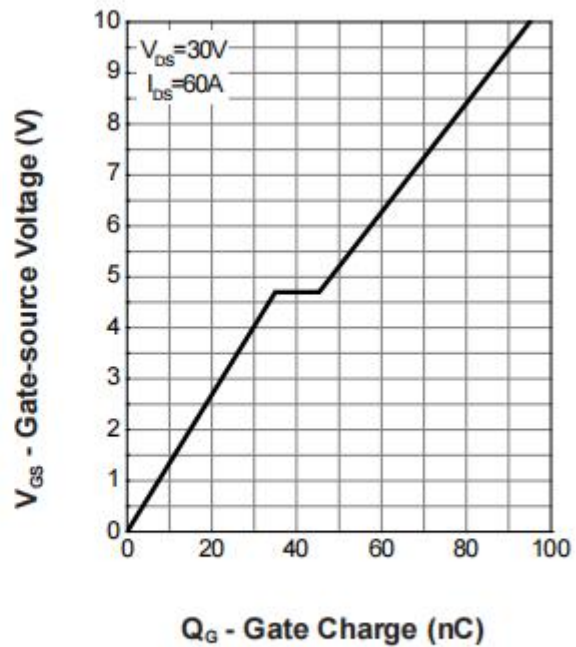


Typical Characteristics (Cont.)

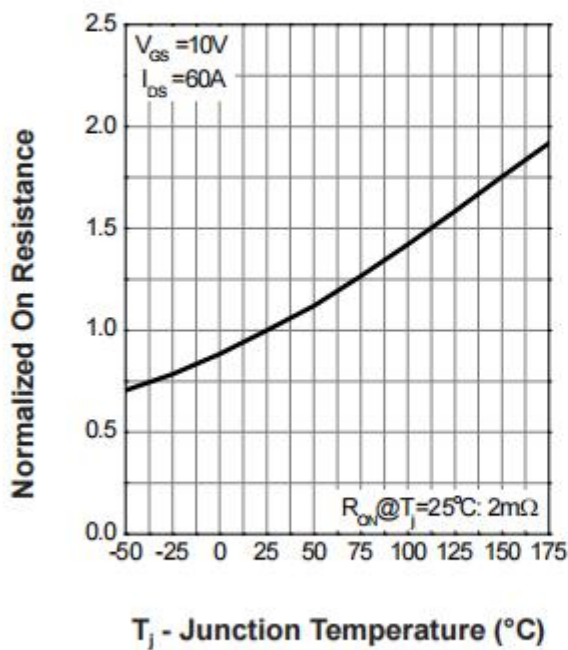
Capacitance



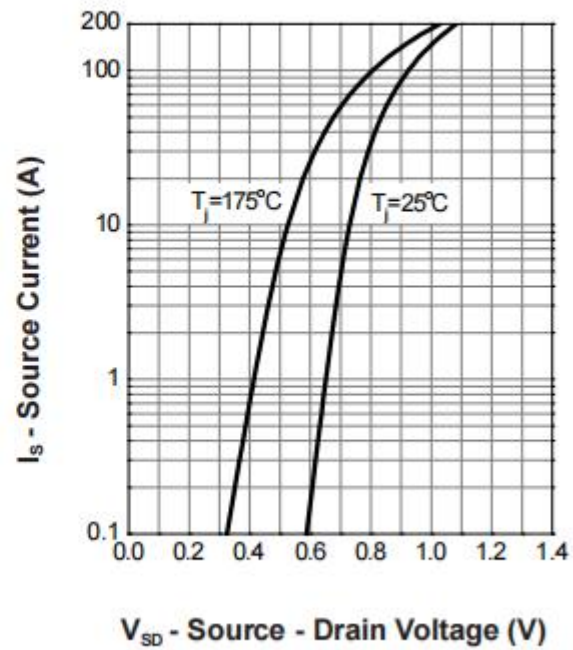
Gate Charge



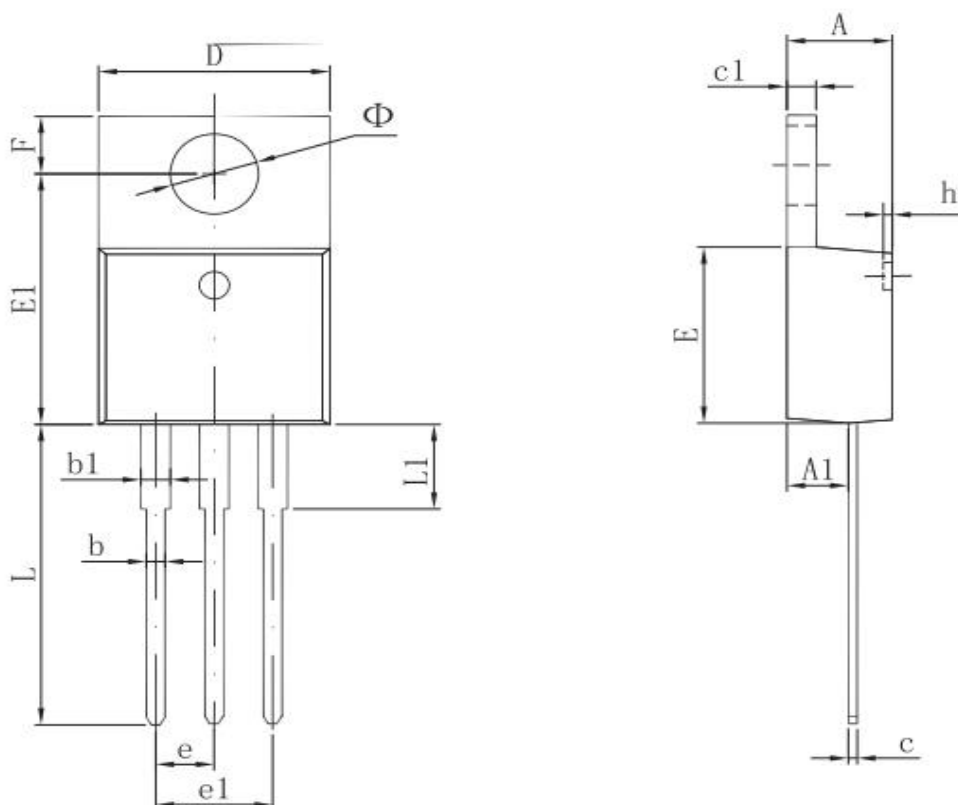
Drain-Source On Resistance



Source-Drain Diode Forward



## Packaging information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.470	4.670	0.176	0.184
A1	2.520	2.820	0.099	0.111
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
E1	12.060	12.460	0.475	0.491
e	2.540 TYP		0.100 TYP	
e1	4.980	5.180	0.196	0.204
F	2.590	2.890	0.102	0.114
h	0.000	0.300	0.000	0.012
L	13.400	13.800	0.528	0.543
L1	3.560	3.960	0.140	0.156
Φ	3.735	3.935	0.147	0.155

## Attention

- 1, Any and all Winsok power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your Winsok power representative nearest you before using any Winsok power products described or contained herein in such applications.
- 2, Winsok power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all Winsok power products described or contained herein.
- 3, Specifications of any and all Winsok power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- 4, Winsok power Semiconductor CO., LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- 5, In the event that any or all Winsok power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- 6, No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of Winsok power Semiconductor CO., LTD.
- 7, Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. Winsok power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- 8, Any and all information described or contained herein are subject to change without notice due to product/technology improvement,etc. When designing equipment, refer to the "Delivery Specification" for the Winsok power product that you intend to use.
- 9, this catalog provides information as of Sep.2014. Specifications and information herein are subject to change without notice.